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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Metal Oxide Varistor Disc type

SIOV-S10K680G5S3

Ordering code: B72210S0681K351

Data sheet

Form: FBLE3K/b

File name: S10K680G5S3_a

MODIFICATIONS: New datasheet

REMARKS:

Dranavad hv	Calling Hunt Pologo		signed: PE / Collins-Hunt			signed: QS / Zödl		
Prepared by	Collins-Hunt	Release	signed:			signed:		
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SIOV nomenclature

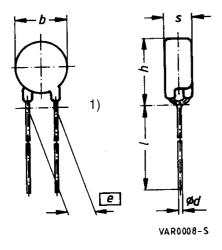
S = Disk type

10 = Rated disk diameter

K = Tolerance of V_V at 1mA: \pm 10%

680 = Max. AC voltage G5 = Taping Style G5 S3 = Crimp style S3

Figure: Dimensions given in Millimeters (mm)



- 1) seating plane in accordance with IEC 60717
- 2) measured above carrier tape

Electrical data:

Maximum Ratings (85°C)

Max. operating AC voltage	V_{RMS}	=	680 V
Max. operating DC voltage	V_{DC}	=	895 V
Surge current (8/20µs) 1 time	I_{max}	=	2500 A
Energy absorption (2ms) 1 time	W_{max}	=	72 J
Average power dissipation	P_{max}	=	0,40 W

Characteristics (25°C)

Varistor voltage at 1mA	V_V	=	1100 V ± 10%
Clamping voltage at 25A (8/20µs)	$V_{C,max}$	=	1815 V
Typ. capacitance at 1 kHz	C	=	85 pF

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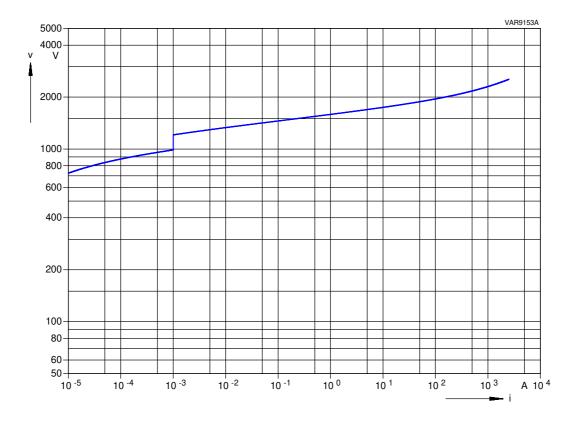
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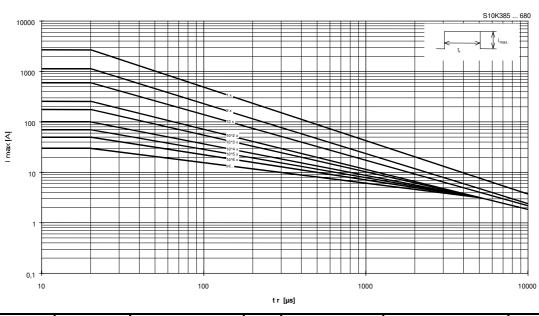
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V/I Characteristic:



Derating:



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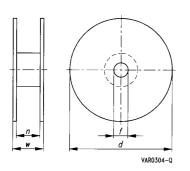
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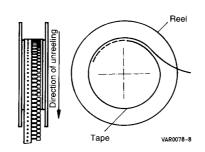
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Taping:

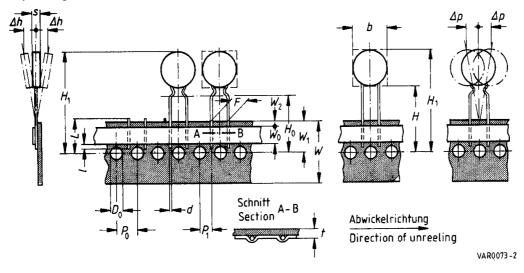
Package Unit: 1000 pcs./reel





 $\begin{array}{lll} d_{max} & = & 500 \text{ mm} \\ w_{max} & = & 72 \text{ mm} \\ f & = & 23 \pm 1,0 \text{ mm} \\ n & = & 59 \text{ mm (typ.)} \end{array}$

Lead spacing 7,5 mm





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Tape dimensions, in Millimeters (mm)

Definition	efinition Symbol Dimension		Tolerance	Remarks
Body diameter	b	12,0	max	
Body thickness	S	7,9	max	
Lead diameter	d	0,8	± 0,05	
Sprocket hole pitch	P _o	12,7	± 0,3	± 1mm/20 sprocket holes
Distance hole center to lead center	P ₁	8,95	± 0,8	
Lead spacing	F	7,5	± 0,8	measured above carrier tape
Component deviation	Δh	Depends on s		measured at top of component body
Component deviation	Δр	0	± 2,0	measured at top of component body
Carrier tape width	W	18,0	± 0,5	
Adhesive tape width	Wo	11,0	min	Peel-off force ≥5N
Sprocket hole position	W ₁	9,0	+0,75/ -0,5	
Adhesive tape position	W ₂	3,0	max	
Distance hole center to the top of the component	H ₁	45	max	
Seating plane height	H ₀	16,0	± 0,5	
Hole diameter	D ₀	4,0	± 0,2	
Total tape thickness	t	0,9	max	
Lead overlap	I	4,0	max	
Cutting level	L	11,0	max	

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Reliability Data:

	Characteristics	Test Methods/Description	Specifications
E	Varistor Voltage	The voltage between two terminals with the specified measuring current applied is called V_v (1 mA _{DC} @ 0.2 - 2 s).	To meet the specified value.
L	Clamping Voltage	The maximum voltage between two terminals with the specified standard impulse current (8/20µs) illustrated below applied.	To meet the specified value.
E		% Peak	
С		100	
Т		10 0 0	
R		T _p Rise Time us T. Decay time to half value us O, Nomrial start In Peak value	
I			
С	Surge current derating,	100 surge currents (8/20 μs), unipolar, interval 30 s, amplitude corresponding to derating curve	∆ V/V (1 mA) ≤ 10 % (measured
Α	8/20 μs	for 20 μs	in direction of surge current) No visible damage
L	Surge current derating, 2 ms	100 surge currents (2ms), unipolar, interval 120s, amplitude corresponding to derating curve for 2ms	Δ V/V (1 mA) ≤ 10 % (measured in direction of surge current) No visible damage

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	Characteristics	Test Methods/Description	Specifications
	Tensile strength	After gradually applying the force specified below and keeping the unit fixed for 10 seconds, the terminal shall be visually examined for any damage.	∆ V/V (1 mA) ≤ 5 % No break of solder joint, no wire break
М		Terminal diameter Force 0.5 mm 5 N 0.6 mm 10 N 0.8 mm 10 N 1.0 mm 20 N	
E	Vibration	After repeatedly applying a single harmonic vibration according to the table below. Thereafter, the unit shall be visually examined.	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage
Н		frequency range: 10 55 Hz amplitude: 0.75 mm or 98 m/s² duration: 6 h (3 x 2 h) pulse: sine wave	
A N	Solderability	After dipping the terminals to a depth of approximately 3 mm from the body in a soldering bath of 235°C for 5 seconds, the terminals shall be visually examined.	The inspection shall be carried out under adequate light with normal eyesight or
ı			with the assistance of a magnifier capable of giving a magnification of 4 times to 10 times.
C			The dipped surface shall be covered with a smooth and
L			bright solder coating with no more than small amounts of scattered
			imperfections such as pinholes or unwetted or de-wetted areas. These imperfections shall not be concentrated in one area.



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	Characteristics	Test Methods/Description	Specifications
М	Resistance to soldering heat	Each lead shall be dipped into a solder bath	\(\Delta \text{V/V} \) (1 mA)
Е	soldering near	having a temperature of $260 \pm 5^{\circ}$ C to a point 2.0 to 2.5 mm from the body of the unit, be held	≤ 5 % No visible damage
С		there for 10 ± 1 s and then be stored at room	
Н		temperature and normal humidity for 1 to 2 hours. The change of V _v and mechanical	
Α		damages shall be examined.	
Ν	Electric strength	2500 V _{RMS} , 10 s	No breakdown
ı		The varistor is placed in a container holding 1.6 \pm 0.2 mm diameter metal balls such that only the	
С		terminations of the varistor are protruding.	
Α		The specified voltage shall be applied between both terminals of the specimen connected	
L		together and the electrode inserted between the metal balls.	

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	Characteristics	Test Methods/Description	Specifications
E N	Max. AC operating voltage	After being continuously applied the maximum allowable voltage at $85 \pm 2^{\circ}\text{C}$ for 1000 hours, the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_{ν} shall be measured.	Δ V/V (1 mA) ≤ 10 %
V	Damp heat, steady state	The specimen shall be subjected to $40 \pm 2^{\circ}\text{C}$, 90 to 95 % r.H. for 56 days without load and then stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_{v} shall be measured.	∆ V/V (1 mA) ≤ 10 %
R	Climatic sequence	The specimen shall be subjected to: a) dry heat at +85°C, 16 h	∆ V/V (1 mA) ≤ 10 %
0		b) damp heat, 1st cycle: 55°C, 93 % r.H., 24 h c) cold, -40°C, 2 h d) damp heat, additional	
N		5 cycles: 55° C, 93% r.H., 24 h/cycle Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. Thereafter, the change of V_v shall be	
М		measured.	
E	Fast temperature cycling	The temperature cycle shown below shall be repeated 5 times. Then the specimen shall be stored at room temperature and normal humidity for 1 to 2 hours. The change of V _v and	$ \Delta \text{ V/V (1 mA)} $ $\leq 5 \%$ No visible damage
N		mechanical damage shall be examined.	
Т		$\begin{array}{cccc} \underline{\text{Step}} & \underline{\text{Temperature (°C)}} & \underline{\text{Period (min.)}} \\ 1 & -40 \pm 3 & 30 \pm 3 \\ 2 & \text{transition time} & < 10 \text{ s} \\ 3 & 85 \pm 2 & 30 \pm 3 \end{array}$	
Α		33 12 33 10	
L			

Note: More details can be found in the data book 'SIOV Metal Oxide Varistors', Ordering No. EPC: 62002-7600

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